

# Jia-Yong Zhang

## List of Publications by Citations

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29  
papers

553  
citations

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h-index

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g-index

32  
ext. papers

727  
ext. citations

4.4  
avg, IF

4.05  
L-index

#	Paper	IF	Citations
29	Strong magnetization and Chern insulators in compressed graphene/CrI <sub>3</sub> van der Waals heterostructures. <i>Physical Review B</i> , <b>2018</b> , 97,	3.3	77
28	Robust quantum anomalous Hall effect in graphene-based van der Waals heterostructures. <i>Physical Review B</i> , <b>2015</b> , 92,	3.3	61
27	Quantum spin Hall and Z <sub>2</sub> metallic states in an organic material. <i>Physical Review B</i> , <b>2014</b> , 90,	3.3	59
26	Abundant topological states in silicene with transition metal adatoms. <i>Physical Review B</i> , <b>2013</b> , 88,	3.3	50
25	Quantum Anomalous Hall Effect in Graphene-based Heterostructure. <i>Scientific Reports</i> , <b>2015</b> , 5, 10629	4.9	41
24	Quantum Spin-Quantum Anomalous Hall Insulators and Topological Transitions in Functionalized Sb(111) Monolayers. <i>Nano Letters</i> , <b>2015</b> , 15, 5149-55	11.5	36
23	Large valley polarization in monolayer MoTe on a magnetic substrate. <i>Physical Chemistry Chemical Physics</i> , <b>2018</b> , 20, 3805-3812	3.6	28
22	Quantum spin-quantum anomalous Hall effect with tunable edge states in Sb monolayer-based heterostructures. <i>Physical Review B</i> , <b>2016</b> , 94,	3.3	25
21	Giant spin-valley polarization and multiple Hall effect in functionalized bismuth monolayers. <i>Npj Quantum Materials</i> , <b>2018</b> , 3,	5	24
20	Quantum anomalous Hall effect in stanene on a nonmagnetic substrate. <i>Physical Review B</i> , <b>2016</b> , 94,	3.3	24
19	Constructive coupling effect of topological states and topological phase transitions in plumbene. <i>Physical Review B</i> , <b>2019</b> , 99,	3.3	14
18	Possible realization of the high-temperature and multichannel quantum anomalous Hall effect in graphene/CrBr heterostructures under pressure. <i>Physical Chemistry Chemical Physics</i> , <b>2019</b> , 21, 17087-17095	2.6	14
17	Chern insulators without band inversion in MoS <sub>2</sub> monolayers with 3d adatoms. <i>Physical Review B</i> , <b>2017</b> , 95,	3.3	12
16	Coupling effect of topological states and Chern insulators in two-dimensional triangular lattices. <i>Physical Review B</i> , <b>2018</b> , 97,	3.3	12
15	Novel Chern insulators with half-metallic edge states. <i>NPG Asia Materials</i> , <b>2018</b> , 10, e467-e467	10.3	11
14	Quantum anomalous Hall effect in real materials. <i>Chinese Physics B</i> , <b>2016</b> , 25, 117308	1.2	11
13	Quantum anomalous Hall effect in stable dumbbell stanene. <i>Applied Physics Letters</i> , <b>2016</b> , 108, 082104	3.4	10

12	Ultrafast all-optical modulation in Fe-doped GaN at 1.31 and 1.55 eV with high contrast and ultralow power. <i>Applied Physics Letters</i> , <b>2017</b> , 110, 161902	3.4	7
11	Prediction of intrinsic two-dimensional non-Dirac topological insulators in triangular metal-organic frameworks. <i>Applied Physics Letters</i> , <b>2019</b> , 114, 043102	3.4	7
10	Topologically trivial states induced by strong spin-orbit coupling and Chern insulators in doped X(C <sub>2</sub> N <sub>3</sub> H <sub>15</sub> ) (X=Ta, Hf) metal-organic frameworks. <i>Physical Review B</i> , <b>2019</b> , 99,	3.3	6
9	Off-centered-symmetry-based band structure modulation of hexagonal WO <sub>3</sub> . <i>Journal of Physics Condensed Matter</i> , <b>2019</b> , 31, 355501	1.8	5
8	Quantum valley Hall states and topological transitions in Pt(Ni, Pd)-decorated silicene: a first-principles study. <i>Journal of Chemical Physics</i> , <b>2014</b> , 141, 244701	3.9	3
7	Strain-modulated electrical and optical bandgaps of tetragonal WO <sub>3</sub> : An HSE06 hybrid functional calculation. <i>AIP Advances</i> , <b>2020</b> , 10, 095202	1.5	3
6	Bipolar ferromagnetic semiconductors and doping-tuned room-temperature half-metallicity in monolayer MoX <sub>3</sub> (X=Cl, Br, I): An HSE06 study. <i>Physical Review B</i> , <b>2021</b> , 103,	3.3	3
5	Water-Dispersible CsPbBr <sub>3</sub> Perovskite Nanocrystals with Ultra-Stability and its Application in Electrochemical CO Reduction. <i>Nano-Micro Letters</i> , <b>2021</b> , 13, 172	19.5	3
4	Coexistence of valley polarization and Chern insulating states in MoS <sub>2</sub> monolayers with n-p codoping. <i>Scientific Reports</i> , <b>2020</b> , 10, 9851	4.9	2
3	Nonvolatile tuning of the Rashba effect in the CuInP <sub>2</sub> S <sub>6</sub> /MoSSe/CuInP <sub>2</sub> S <sub>6</sub> heterostructure. <i>Journal of Applied Physics</i> , <b>2020</b> , 128, 224105	2.5	2
2	Robust quantum anomalous Hall effect with electrically tunable band gap in Ta-decorated silicene. <i>Applied Physics Letters</i> , <b>2019</b> , 114, 053105	3.4	1
1	Trigonal multivalent polonium monolayers with intrinsic quantum spin Hall effects.. <i>Scientific Reports</i> , <b>2022</b> , 12, 2129	4.9	0